19-0299; Rev. 2; 7/96

MAXIM

Precision, 8-Channel/Dual 4-Channel, Low-Voltage, CMOS Analog Multiplexers

General Description

The MAX398/MAX399 precision, monolithic, CMOS analog multiplexers (muxes) offer low on-resistance (less than 100Ω), which is matched to within 6Ω between channels and remains flat over the specified analog signal range (11Ω max). They also offer low leakage over temperature (NO-off leakage current less than 2.5nA at +85°C) and fast switching speeds (transition time less than 250ns). The MAX398 is an 8-channel device, and the MAX399 is a dual 4-channel device.

The MAX398/MAX399 are fabricated with Maxim's low-voltage silicon-gate process. Design improvements yield extremely low charge injection (less than 5pC) and guarantee electrostatic discharge protection greater than 2000V.

These muxes operate with a single +3V to +15V supply or bipolar ±3V to ±8V supplies, while retaining CMOS-logic input compatibility and fast switching. CMOS inputs provide reduced input loading. The MAX398/MAX399 are pin compatible with the industry-standard DG408, DG409, DG508A, and DG509A.

Applications

Sample-and-Hold Circuits
Automatic Test Equipment
Heads-Up Displays
Guidance and Control Systems
Military Radios
Communications Systems
Battery-Operated Systems
PBX, PABX
Audio Signal Routing
Low-Voltage Data Acquisition Systems

Features

- **Pin Compatible with Industry-Standard DG408/DG409/DG508A/DG509A**
- **Guaranteed On-Resistance Match Between Channels (<6Ω)**
- **Low On-Resistance (<100Ω)**
- **Guaranteed Flat On-Resistance over Signal Range (<11Ω)**
- **Guaranteed Low Charge Injection (<5pC)**
- **NO-Off Leakage Current <1nA at +85°C**
- **COM-Off Leakage Current <2.5nA at +85°C**
- **Electrostatic Discharge Protection >2000V**
- **Single-Supply Operation (+3V to +15V) Bipolar-Supply Operation (±3V to ±8V)**
- **Low Power Consumption (<300µW)**
- **Rail-to-Rail Signal Handling**
- **TTL/CMOS-Logic Compatible**

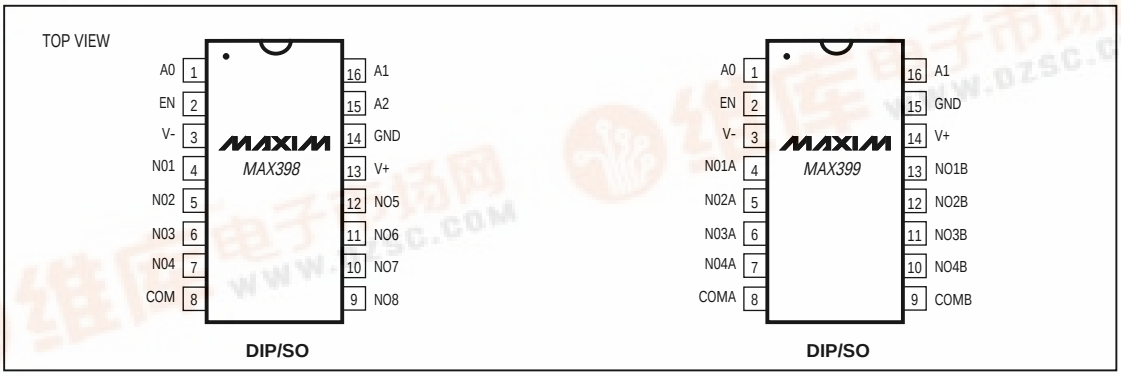
Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX398CPE	0°C to +70°C	16 Plastic DIP
MAX398CSE	0°C to +70°C	16 Narrow SO
MAX398C/D	0°C to +70°C	Dice*
MAX398EPE	-40°C to +85°C	16 Plastic DIP
MAX398ESE	-40°C to +85°C	16 Narrow SO
MAX398EJE	-40°C to +85°C	16 CERDIP**
MAX398MJE	-55°C to +125°C	16 CERDIP**

Ordering Information continued at end of data sheet.

** Contact factory for dice specifications.*
*** Contact factory for package availability.*

Pin Configurations



Precision, 8-Channel/Dual 4-Channel, Low-Voltage, CMOS Analog Multiplexers

ABSOLUTE MAXIMUM RATINGS

Voltage Referenced to GND
- V+ .....-0.3V to +17V
- V- .....+0.3V to -17V
- V+ to V-.....-0.3V to +17V

Voltage into Any Terminal (Note 1).....(V- - 2V) to (V+ + 2V) or 30mA (whichever occurs first)
Current into Any Terminal 30mA
Peak Current, Any Terminal
- (pulsed at 1ms, 10% duty cycle max) 40mA

Continuous Power Dissipation (T_A = +70°C)
- Plastic DIP (derate 7.5mW/°C above +70°C) 470mW
- Narrow SO (derate 8.7mW/°C above +70°C) 696mW
- CERDIP (derate 10.0mW/°C above +70°C).....900mW

Operating Temperature Ranges
- MAX39_C_ _ .....0°C to +70°C
- MAX39_E_ _.....-40°C to +85°C
- MAX39_MJE .....-55°C to +125°C

Storage Temperature Range .....-65°C to +150°C
Lead Temperature (soldering, 10sec) .....+300°C

Note 1: Signals on any terminal exceeding V+ or V- are clamped by internal diodes. Limit forward current to maximum current ratings.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

(V+ = +5V ±10%, V- = -5V ±10%, GND = 0V, $V_{AH} = V_{ENH}$ = +2.4V, $V_{AL} = V_{ENL}$ = +0.8V, $T_A = T_{MIN}$ to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS				MIN	TYP (Note 2)	MAX	UNITS
SWITCH									
Analog Signal Range	V_{COM}, V_{NO}	(Note 3)				V-		V+	V
Channel On-Resistance	R_{ON}	I_{NO} = 1mA, V_{COM} = ±3.5V		T_A = +25°C			60	100	Ω
				$T_A = T_{MIN}$ to T_{MAX}				125	
R_{ON} Matching Between Channels (Note 4)	ΔR_{ON}	I_{NO} = 1mA, V_{COM} = ±3.5V, V+ = 5V, V- = -5V		T_A = +25°C				6	Ω
				$T_A = T_{MIN}$ to T_{MAX}				8	
On-Resistance Flatness (Note 5)	$R_{FLAT(ON)}$	I_{NO} = 1mA, V_{COM} = ±3V, V+ = 5V, V- = -5V		T_A = +25°C				11	Ω
				$T_A = T_{MIN}$ to T_{MAX}				14	
NO-Off Leakage Current (Note 6)	$I_{NO(OFF)}$	V_{NO} = ±4.5V, V_{COM} = ∓4.5V, V+ = 5.5V, V- = -5.5V		T_A = +25°C		-0.1		0.1	nA
				$T_A = T_{MIN}$ to T_{MAX}	C, E	-1.0		1.0	
					M	-10		10	
COM-Off Leakage Current (Note 6)	$I_{COM(OFF)}$	V_{COM} = ±4.5V, V_{NO} = ∓4.5V, V+ = 5.5V, V- = -5.5V	MAX398	T_A = +25°C		-0.2		0.2	nA
				$T_A = T_{MIN}$ to T_{MAX}	C, E	-2.5		2.5	
					M	-20		20	
		V_{COM} = ±4.5V, V_{NO} = ∓4.5V, V+ = 5.5V, V- = -5.5V	MAX399	T_A = +25°C		-0.1		0.1	
				$T_A = T_{MIN}$ to T_{MAX}	C, E	-1.5		1.5	
					M	-10		10	
COM-On Leakage Current (Note 6)	$I_{COM(ON)}$	V_{COM} = ±4.5V, V_{NO} = 4.5V,	MAX398	T_A = +25°C		-0.4		0.4	nA
				$T_A = T_{MIN}$ to T_{MAX}	C, E	-5		5	
					M	-40		40	
			MAX399	T_A = +25°C		-0.2		0.2	
				$T_A = T_{MIN}$ to T_{MAX}	C, E	-2.5		2.5	
					M	-20		20	

ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

(V+ = +5V ±10%, V- = -5V ±10%, GND = 0V, $V_{AH} = V_{ENH} = +2.4V$, $V_{AL} = V_{ENL} = +0.8V$, $T_A = T_{MIN}$ to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP (Note 2)	MAX	UNITS
DIGITAL LOGIC INPUT								
Logic High Input Voltage	V_{AH}, V_{ENH}			$T_A = T_{MIN}$ to T_{MAX}	2.4			V
Logic Low Input Voltage	V_{AL}, V_{ENL}			$T_A = T_{MIN}$ to T_{MAX}			0.8	V
Input Current with Input Voltage High	I_{AH}, I_{ENH}	$V_A = V_{EN} = 2.4V$			-0.1		0.1	µA
Input Current with Input Voltage Low	I_{AL}, I_{ENL}	$V_A = V_{EN} = 0.8V$			-0.1		0.1	µA
SUPPLY								
Power-Supply Range					±3		±8	V
Positive Supply Current	I+	$V_{EN} = V_A = 0V/V+$, V+ = 5.5V, V- = -5.5V		$T_A = +25°C$	-1		1	µA
Negative Supply Current	I-	$V_{EN} = V_A = 0V/V+$, V+ = 5.5V, V- = -5.5V		$T_A = T_{MIN}$ to T_{MAX}	-1		1	µA
Ground Current	I_{GND}	$V_{EN} = V_A = 0V/V+$, V+ = 5.5V, V- = -5.5V		$T_A = +25°C$	-1		1	µA
				$T_A = T_{MIN}$ to T_{MAX}	-1		1	
DYNAMIC								
Transition Time	t_{TRANS}	Figure1					150	ns
Break-Before-Make Interval	t_{OPEN}	Figure 2		$T_A = +25°C$	0	40		ns
Enable Turn-On Time	$t_{ON(EN)}$	Figure 3		$T_A = +25°C$		60	150	ns
				$T_A = T_{MIN}$ to T_{MAX}			250	
Enable Turn-Off Time	$t_{OFF(EN)}$	Figure 3		$T_A = +25°C$		40	150	ns
				$T_A = T_{MIN}$ to T_{MAX}			200	
Charge Injection (Note 3)	Q	$C_L = 10nF$, $V_S = 0V$, $R_S = 0\Omega$		$T_A = +25°C$		2	5	pC
Off Isolation (Note 7)		$V_{EN} = 0V$, $R_L = 1k\Omega$, f = 100kHz		$T_A = +25°C$		-75		dB
Crosstalk Between Channels	V_{CT}	$V_{EN} = 2.4V$, f = 100kHz, $V_{GEN} = 1V_{p-p}$, $R_L = 1k\Omega$		$T_A = +25°C$		-92		dB
Logic Input Capacitance	C_{IN}	f = 1MHz		$T_A = +25°C$		8		pF
NO-Off Capacitance	$C_{NO(OFF)}$	f = 1MHz, $V_{EN} = V_D = 0V$		$T_A = +25°C$		11		pF
COM-Off Capacitance	$C_{COM(OFF)}$	f = 1MHz, $V_{EN} = V_D = 0V$	MAX398	$T_A = +25°C$		40		pF
			MAX399			20		
COM-On Capacitance	$C_{COM(ON)}$	f = 1MHz, $V_{EN} = V_D = 0V$	MAX398	$T_A = +25°C$		54		pF
			MAX399			34		

ELECTRICAL CHARACTERISTICS—Single 5V

(V+ = 5V ±10%, V- = 0V, GND = 0V, V_{AH} = V_{ENH} = +2.4V, V_{AL} = V_{ENL} = +0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS				MIN	TYP (Note 2)	MAX	UNITS
SWITCH									
Analog Signal Range	V_{COM}, V_{NO}	(Note 3)				V-		V+	V
On-Resistance	R_{ON}	I_{NO} = 1mA, V_{COM} = 3.5V, V+ = 4.5V		T_A = +25°C			150	225	Ω
				T_A = T_{MIN} to T_{MAX}				280	
R_{ON} Matching Between Channels (Note 4)	ΔR_{ON}	I_{NO} = 1mA, V_{COM} = 3.5V, V+ = 4.5V		T_A = +25°C				11	Ω
				T_A = T_{MIN} to T_{MAX}				13	
On-Resistance Flatness	R_{FLAT}	I_{NO} = 1mA; V_{COM} = 3V, 2V, 1V; V+ = 5V		T_A = +25°C			10	18	Ω
				T_A = T_{MIN} to T_{MAX}			15	22	
NO-Off Leakage Current (Note 8)	$I_{NO(OFF)}$	V_{NO} = 4.5V, V_{COM} = 0V, V+ = 5.5V		T_A = +25°C		-0.1		0.1	nA
				T_A = T_{MIN} to T_{MAX}	C, E	-1.0		1.0	
					M	-10		10	
COM-Off Leakage Current (Note 8)	$I_{COM(OFF)}$	V_{COM} = 4.5V, V_{NO} = 0V, V+ = 5.5V	MAX398	T_A = +25°C		-0.2		0.2	nA
				T_A = T_{MIN} to T_{MAX}	C, E	-2.5		2.5	
					M	-20		20	
		V_{COM} = 4.5V, V_{NO} = 0V, V+ = 5.5V	MAX399	T_A = +25°C		-0.2		0.2	
				T_A = T_{MIN} to T_{MAX}	C, E	-1.5		1.5	
					M	-10		10	
COM-On Leakage Current (Note 8)	$I_{COM(ON)}$	V_{COM} = 4.5V, V_{NO} = 4.5V, V+ = 5.5V	MAX398	T_A = +25°C		-0.4		0.4	nA
				T_A = T_{MIN} to T_{MAX}	C, E	-5		5	
					M	-40		40	
			MAX399	T_A = +25°C		-0.2		0.2	
				T_A = T_{MIN} to T_{MAX}	C, E	-2.5		2.5	
					M	-20		20	
DIGITAL LOGIC INPUT									
Logic High Input Voltage	V_{AH}, V_{ENH}			T_A = T_{MIN} to T_{MAX}		2.4			V
Logic Low Input Voltage	V_{AL}, V_{ENL}			T_A = T_{MIN} to T_{MAX}				0.8	V
Input Current with Input Voltage High	I_{AH}, I_{ENH}	V_A = V_{EN} = 2.4V				-0.1		0.1	µA
Input Current with Input Voltage Low	I_{AL}, I_{ENL}	V_A = 0V, V_{EN} = 0.8V				-0.1		0.1	µA
SUPPLY									
Power-Supply Range						3		15	V
Positive Supply Current	I+	V_{EN} = V_A = 0V, V+; V+ = 5.5V; V- = 0V				-1.0		1.0	µA
Negative Supply Current	I-	V_{EN} = V_A = 0V, V+; V+ = 5.5V; V- = 0V				-1.0		1.0	µA
I_{GND} Supply Current	I_{GND}	V_{EN} = V+, 0V; V_A = 0V; V+ = 5.5V; V- = 0V		T_A = +25°C		-1.0		1.0	µA
				T_A = T_{MIN} to T_{MAX}		-1.0		1.0	

ELECTRICAL CHARACTERISTICS—Single 5V (continued)

(V+ = 5V ±10%, V- = 0V, GND = 0V, $V_{AH} = V_{ENH}$ = +2.4V, $V_{AL} = V_{ENL}$ = +0.8V, $T_A = T_{MIN}$ to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
DYNAMIC							
Transition Time	t_{TRANS}	V_{NO} = 3V			90	245	ns
Break-Before-Make Interval	t_{OPEN}		T_A = +25°C	10	40		ns
Enable Turn-On Time	$t_{ON(EN)}$		T_A = +25°C		90	200	ns
			$T_A = T_{MIN}$ to T_{MAX}			275	
Enable Turn-Off Time	$t_{OFF(EN)}$		T_A = +25°C		50	125	ns
			$T_A = T_{MIN}$ to T_{MAX}			200	
Charge Injection (Note 3)	Q	C_L = 10nF, V_S = 0V, R_S = 0Ω	T_A = +25°C		1.5	5	pC

ELECTRICAL CHARACTERISTICS—Single 3V

(V+ = 3V ±10%, V- = 0V, GND = 0V, $V_{AH} = V_{ENH}$ = +2.4V, $V_{AL} = V_{ENL}$ = +0.8V, $T_A = T_{MIN}$ to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
SWITCH							
Analog Signal Range	V_{ANALOG}	(Note 3)		V-		V+	V
On-Resistance	R_{ON}	I_{NO} = 1mA, V_{COM} = 1.5V, V+ = 3V	T_A = +25°C		230	375	Ω
			$T_A = T_{MIN}$ to T_{MAX}			425	
DYNAMIC							
Transition Time (Note 3)	t_{TRANS}	Figure 1, V_{IN} = 2.4V, V_{N01} = 1.5V, V_{N08} = 0V	T_A = +25°C		230	575	ns
Enable Turn-On Time (Note 3)	$t_{ON(EN)}$	Figure 3, V_{INH} = 2.4V, V_{INL} = 0V, V_{N01} = 1.5V	T_A = +25°C		200	500	ns
Enable Turn-Off Time (Note 3)	$t_{OFF(EN)}$	Figure 3, V_{INH} = 2.4V, V_{INL} = 0V, V_{N01} = 1.5V	T_A = +25°C		75	400	ns
Charge Injection (Note 3)	Q	C_L = 10nF, V_S = 0V, R_S = 0Ω	T_A = +25°C		1	5	pC

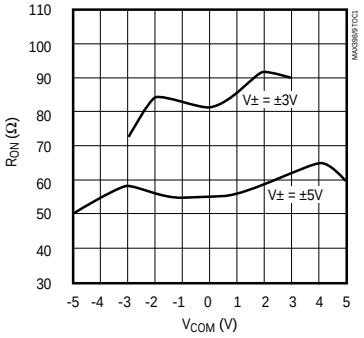
Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.
Note 3: Guaranteed by design.
Note 4: $\Delta R_{ON} = R_{ON}MAX - R_{ON}MIN$.
Note 5: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges, i.e., V_{NO} = 3V to 0V and 0V to -3V.
Note 6: Leakage parameters are 100% tested at maximum rated hot operating temperature, and guaranteed by correlation at +25°C.
Note 7: Worst-case isolation is on channel 4 because of its proximity to the COM pin. Off isolation = 20log V_{COM}/V_{NO}, V_{COM} = output, V_{NO} = input to off switch.
Note 8: Leakage testing at single supply is guaranteed by correlation testing with dual supplies.

Precision, 8-Channel/Dual 4-Channel, Low-Voltage, CMOS Analog Multiplexers

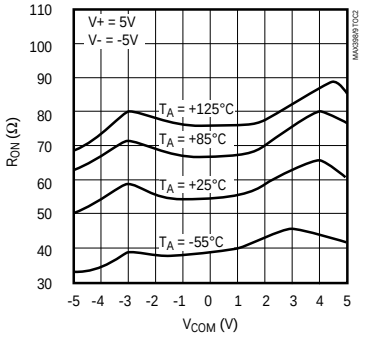
Typical Operating Characteristics

(T_A = +25°C, unless otherwise noted.)

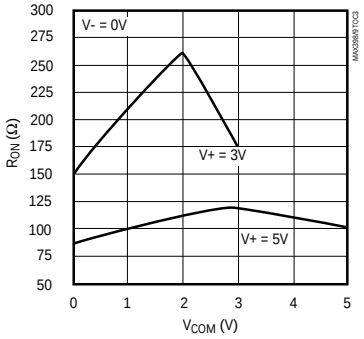
ON-RESISTANCE vs. V_{COM} (DUAL SUPPLIES)



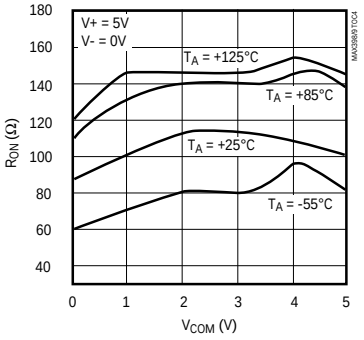
ON-RESISTANCE vs. V_{COM} AND TEMPERATURE (DUAL SUPPLIES)



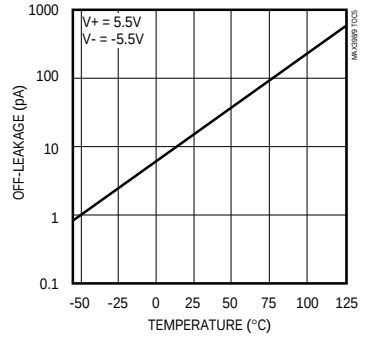
ON-RESISTANCE vs. V_{COM} (SINGLE SUPPLY)



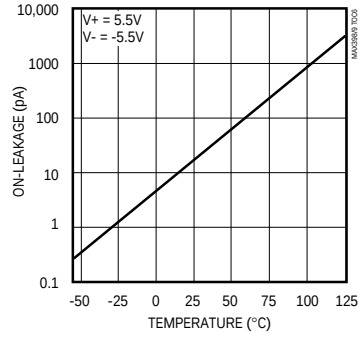
ON-RESISTANCE vs. V_{COM} AND TEMPERATURE (SINGLE SUPPLY)



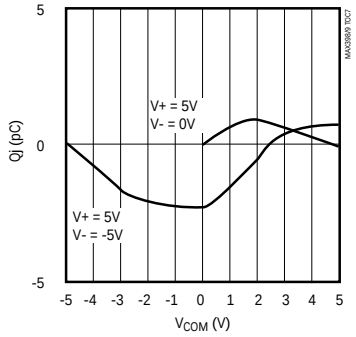
OFF-LEAKAGE vs. TEMPERATURE



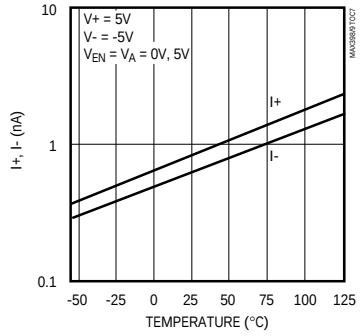
ON-LEAKAGE vs. TEMPERATURE



CHARGE INJECTION vs. V_{COM}



SUPPLY CURRENT vs. TEMPERATURE



Pin Description

PIN		NAME	FUNCTION
MAX398	MAX399		
1, 15, 16	—	A0, A2, A1	Address Inputs
—	1, 16	A0, A1	Address Inputs
2	2	EN	Enable Input, connect to V+ if not used
3	3	V-	Negative Supply Voltage Input
4–7	—	NO1–NO4	Analog Inputs—bidirectional
—	4–7	NO1A–NO4A	Analog Inputs—bidirectional
8	—	COM	Analog Output—bidirectional
—	8, 9	COMA, COMB	Analog Outputs—bidirectional
9–12	—	NO8–NO5	Analog Inputs—bidirectional
—	10–13	NO4B–NO1B	Analog Inputs—bidirectional
13	14	V+	Positive Supply Voltage Input
14	15	GND	Ground

Precision, 8-Channel/Dual 4-Channel, Low-Voltage, CMOS Analog Multiplexers

Applications Information

Operation with Supply Voltages Other than ±5V

Using supply voltages less than ±5V reduces the analog signal range. The MAX398/MAX399 muxes operate with ±3V to ±8V bipolar supplies or with a +3V to +15V single supply. Connect V- to GND when operating with a single supply. Both device types can also operate with unbalanced supplies, such as +10V and -5V. The *Typical Operating Characteristics* graphs show typical on-resistance with ±3V, ±5V, +3V and +5V supplies. (Switching times increase by a factor of two or more for operation at 5V.)

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, then V-, followed by the logic inputs, NO, or COM. If power-supply sequencing is not possible, add two small signal diodes (D1, D2) in series with supply pins for overvoltage protection (Figure 1). Adding diodes reduces the analog signal range to one diode drop below V+ and one diode drop above V-, but does not affect the devices' low switch resistance and low leakage characteristics. Device operation is unchanged, and the difference between V+ and V- should not exceed 17V. These protection diodes are not recommended when using a single supply.

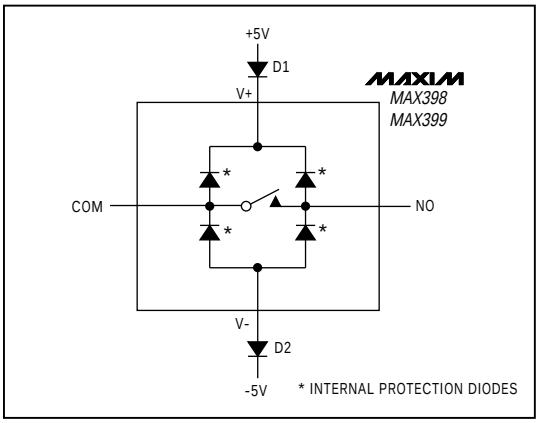


Figure 1. Overvoltage Protection Using External Blocking Diodes

Test Circuits/Timing Diagrams

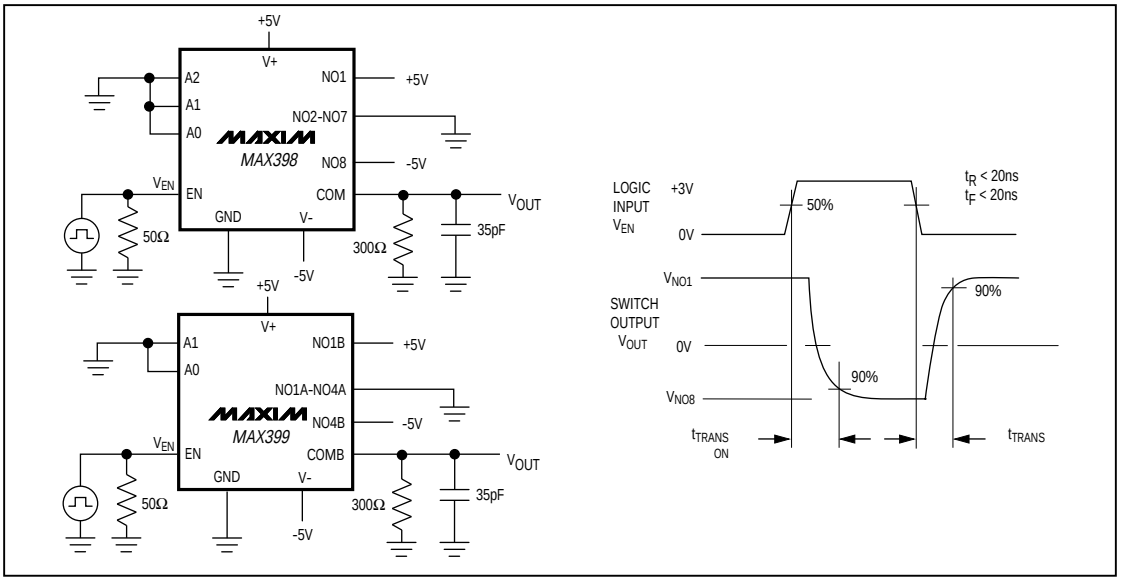


Figure 2. Transition Time

Test Circuits/Timing Diagrams (continued)

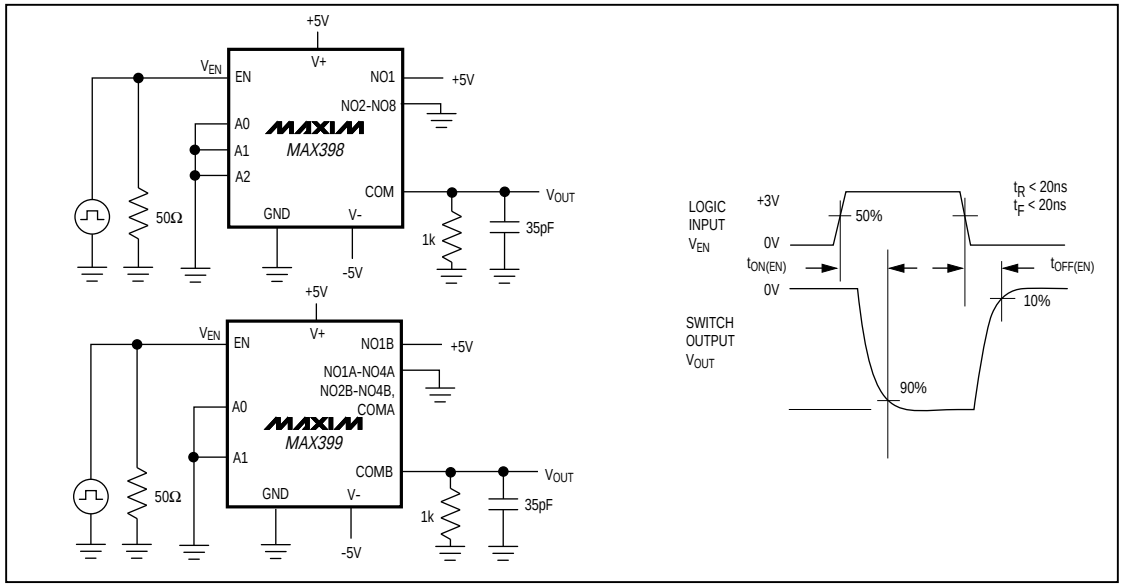


Figure 3. Enable Switching Time

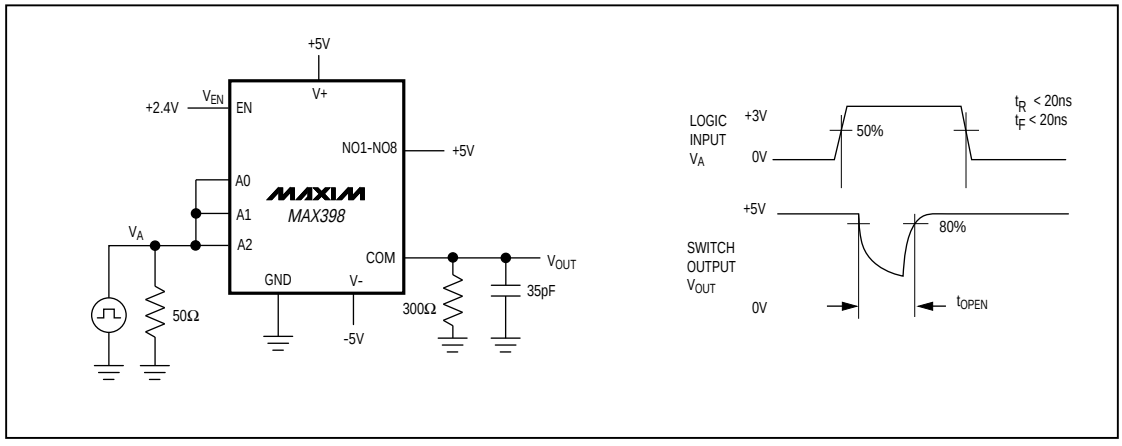


Figure 4. Break-Before-Make Interval

Precision, 8-Channel/Dual 4-Channel, Low-Voltage, CMOS Analog Multiplexers

Test Circuits/Timing Diagrams (continued)

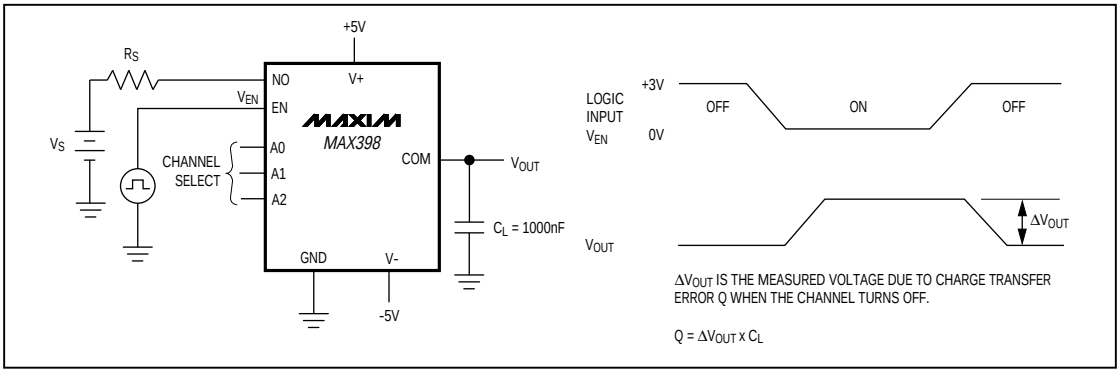


Figure 5. Charge Injection

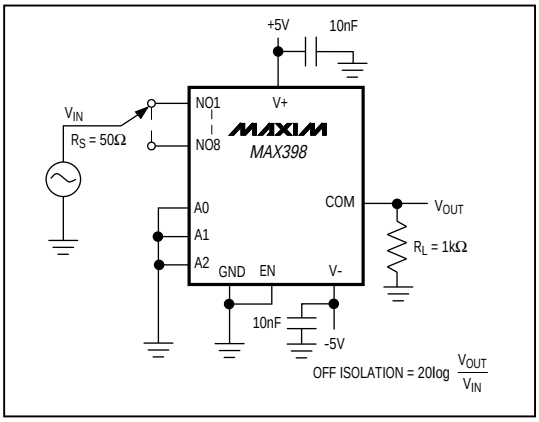


Figure 6. Off Isolation

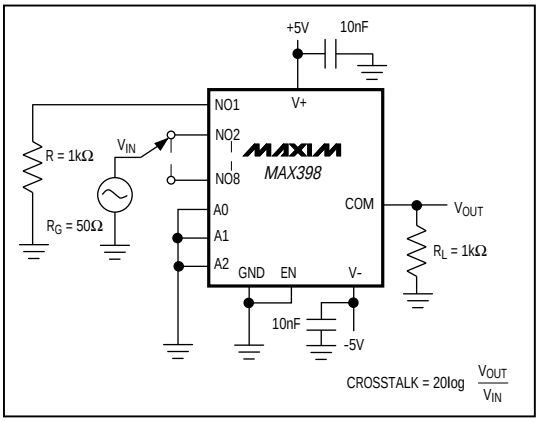


Figure 7. Crosstalk

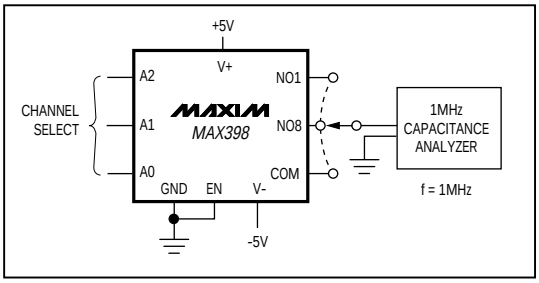
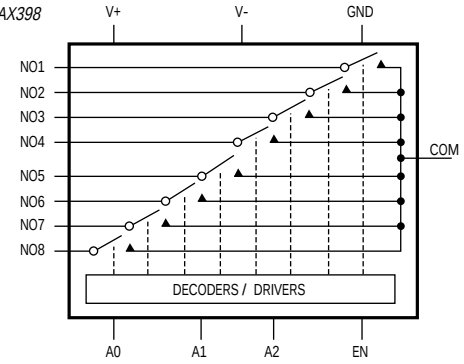


Figure 8. NO/COM Capacitance

Functional Diagrams/Truth Tables

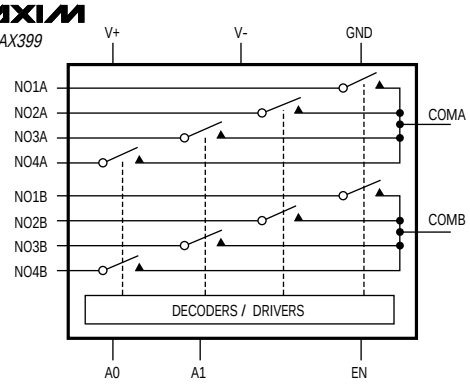
MAXIM

MAX398



MAXIM

MAX399



MAX398				
A2	**A1**	**A0**	**EN**	**ON SWITCH**
X	X	X	0	NONE
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8

MAX399			
A1	**A0**	**EN**	**ON SWITCH**
X	X	0	NONE
0	0	1	1
0	1	1	2
1	0	1	3
1	1	1	4

LOGIC "0" $V_{AL} \leq +0.8$ V, LOGIC "1" $V_{AH} \geq +2.4$ V

Precision, 8-Channel/Dual 4-Channel, Low-Voltage, CMOS Analog Multiplexers

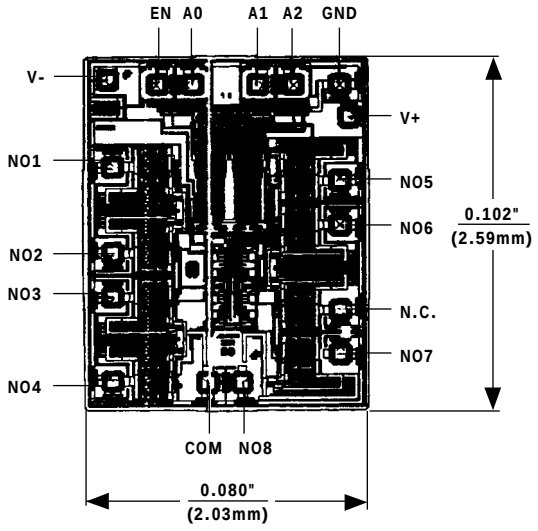
_Ordering Information (continued)

PART	TEMP. RANGE	PIN-PACKAGE
MAX399CPE	0°C to +70°C	16 Plastic DIP
MAX399CSE	0°C to +70°C	16 Narrow SO
MAX399C/D	0°C to +70°C	Dice*
MAX399EPE	-40°C to +85°C	16 Plastic DIP
MAX399ESE	-40°C to +85°C	16 Narrow SO
MAX399EJE	-40°C to +85°C	16 CERDIP**
MAX399MJE	-55°C to +125°C	16 CERDIP**

** Contact factory for dice specifications.*
*** Contact factory for package availability.*

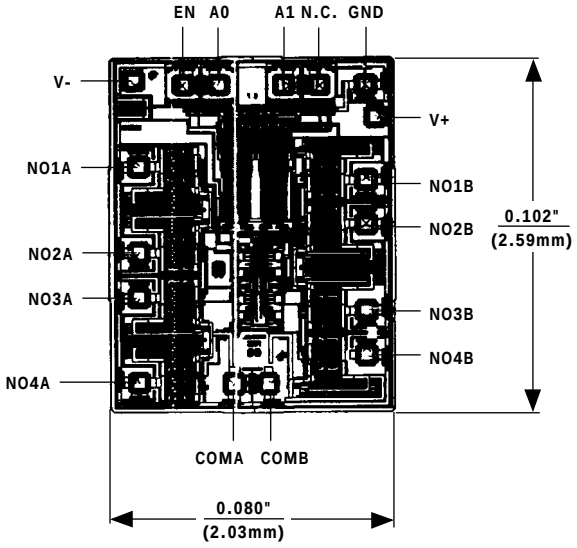
_Chip Topographies

MAX398



TRANSISTOR COUNT: 161
SUBSTRATE CONNECTED TO V+

MAX399



TRANSISTOR COUNT: 161
SUBSTRATE CONNECTED TO V+